NSN 5961-01-326-3630

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-326-3630 **Inclosure Material:** Plastic **Overall Length:** 0.593 inches **Overall Height:** 0.187 inches **Overall Width:** 0.375 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 400.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 250.00 microamperes zero-gate-voltage drain current and 500.00 nanoamperes reverse gate current with all other terminals short-circuit to source, junction-gate **Power Rating Per Characteristic:** 75.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli